Features

- Slew rate—2500 V/μs
- Rise time—1 ns
- Bandwidth—350 MHz
- ELH0033—pin compatible
- ± 5 to ± 15 V operation
- 100 mA output current
- MIL-STD-883B Rev. C devices manufactured in U.S.A.

Applications

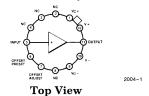
- Coaxial cable driver
- Fast op amp booster
- Flash converter driver
- Video line driver
- High-speed sample and hold
- Pulse transformer driver
- A.T.E. pin driver

Ordering Information

Part No.	Temp. Range	Package	Outline#
EL2004CG	-25°C to +85°C	TO-8	MDP0002
EL2004G	-55°C to +125°C	TO-8	MDP0002
EL2004L	-55°C to +125°C	52-Pad LCC	MDP0013
EL2004L/MI	L -55°C to +125°C	52-Pad LCC	MDP0013
5962-89659	is the SMD ver	sion of th	is device.

Connection Diagram

Case is Electrically Isolated



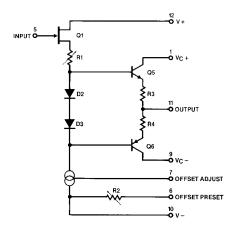
General Description

The EL2004 is a very high-speed, FET input buffer/line driver designed for unity gain applications at both high current (up to 100 mA) and at frequencies up to 350 MHz. The 2500 V/ μ s slew rate and wide bandwidth ensures the stability of the circuit when the EL2004 is used inside op amp feedback loops.

Applications for the EL2004 include line drivers, video buffers, wideband instrumentation, and high-speed drivers for inductive and capacitive loads. The performance of the EL2004 makes it an ideal buffer for video applications including input buffers for flash A/D converters, and output buffers for video DACs. Its excellent phase linearity is particularly advantageous in digital signal processing applications.

Elantec facilities comply with MIL-I-45208A and are MIL-STD-1772 certified. Elantec's Military devices comply with MIL-STD-883B Revision C and are manufactured in our rigidly controlled, ultra-clean facilities in Milpitas, California. For additional information on Elantec's Quality and Reliability Assurance Policy and procedures request brochure QRA-1.

Simplified Schematic



2004-3

Note: All information contained in this data sheet has been carefully checked and is believed to be accurate as of the date of publication; however, this data sheet cannot be a "controlled document". Current revisions, if any, to these specifications are maintained at the factory and are available upon your request. We recommend checking the revision level before finalization of your design documentation. Patent pending.

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Absolute Maximum Ratings $(T_A = 25^{\circ}C)$

v_s	Supply Voltage $(V + - V -)$	40V	$T_{\mathbf{A}}$	Operating Temperature Range	
v_{in}	Input Voltage	40 V		EL2004	-55° C to $+125^{\circ}$ C
P_{D}	Power Dissipation (See curves)	1.5W		EL2004C	-25°C to $+85$ °C
I _{OC}	Continuous Output Current	$\pm 100 \ mA$	$T_{ m J}$	Operating Junction Temperature	175°C
I _{OP}	Peak Output Current	$\pm250~\mathrm{mA}$	T_{ST}	Storage Temperature	-65° C to $+150^{\circ}$ C
				Lead Temperature	
				(Soldering, 10 seconds)	300°C

Important Note

All parameters having Min/Max specifications are guaranteed. The Test Level column indicates the specific device testing actually performed during production and Quality inspection. Elantec performs most electrical tests using modern high-speed automatic test equipment, specifically the LTX77 Series system. Unless otherwise noted, all tests are pulsed tests, therefore $T_J = T_C = T_A$.

Test Procedure
100% production tested and QA sample tested per QA test plan QCX0002.
100% production tested at $T_{ m A}=25^{\circ}{ m C}$ and QA sample tested at $T_{ m A}=25^{\circ}{ m C}$,
$ m T_{MAX}$ and $ m T_{MIN}$ per QA test plan QCX0002.
QA sample tested per QA test plan QCX0002.
Parameter is guaranteed (but not tested) by Design and Characterization Data.
Parameter is typical value at $T_A = 25^{\circ}C$ for information purposes only.

\pm 15V DC Electrical Characteristics

 $\rm V_S=\,\pm\,15V,\,T_{MIN} \leq T_A \leq T_{MAX},\,V_{IN}=0V,\,R_L=1\,k\Omega$ unless otherwise specified (Note 1)

				EL	2004						
Parameter	Description	Test Conditions Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units	
V _{OS}	Output Offset	$R_{S} \leq 100 \text{ k}\Omega, T_{J} = 25^{\circ}\text{C}$		5	10	I		12	20	I	mV
	Voltage	$R_{S} \leq 100 \ k\Omega$			15	I			25	III	mV
A_{V}	Voltage Gain	$V_{IN} = \pm 10V$	0.97	0.98	1.0	I	0.96	0.98	1.0	II	V/V
		$R_{L} = 100\Omega, V_{IN} = \pm 10V$	0.92	0.95	0.98	I	0.90	0.95	0.98	II	V/V
R _{IN}	Input Impedance	$T_{J} = 25^{\circ}C, V_{IN} = \pm 1V$	108	1011		I	108	10 ¹¹		I	Ω
R _{OUT}	Output Impedance	$V_{\rm IN} = \pm 1 V_{\rm DC},$ $\Delta R_{\rm L} = 100 \Omega$ to Infinity		4	8	I		4	10	II	Ω
v _o	Output Voltage	$V_{IN} = \pm 14V$	±12	±13		I	±12	±13		II	V
	Swing	$V_{\mathrm{IN}} = \pm 10.5 \mathrm{V}, R_{\mathrm{L}} = 100 \Omega$ $T_{\mathrm{A}} = 25^{\circ}\mathrm{C}$	±9	±9.8		I	±9	±9.8		I	v
I _{IN}	Input Current	$T_{\rm J} = 25^{\circ}{\rm C} ({\rm Note}2)$			0.25	I			2.0	I	nA
		$T_A = 25^{\circ}C \text{ (Note 3)}$			2.5	IV			20	IV	nA
		$T_{J} = T_{A} = T_{MAX}$			10	I			50	III	nA
		$V_{IN} = -10V$		20		V		20		V	nA
I_S	Supply Current			20	24	I		20	24	II	mA

\pm 5V DC Electrical Characteristics

 $\rm V_S=\,\pm\,5V,\,T_{MIN} \leq T_A \leq T_{MAX},\,V_{IN}=\,0V,\,R_L=\,50\Omega$ unless otherwise specified

				EL	2004						
Parameter	Description	Test Conditions Min Typ	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units	
Vos	Output Offset	$R_{ m S} \leq 100~{ m k}\Omega, T_{ m J} = 25^{\circ}{ m C}$		10	30	I		10	30	I	mV
	Voltage	$R_{S} \leq 100 \ k\Omega$			35	I			35	III	mV
A_V	Voltage Gain	$V_{\rm IN} = \pm 1 V, R_{\rm L} = 1 \mathrm{k}\Omega$	0.90	0.95	1.0	I	0.90	0.95	1.0	II	V/V
		$V_{IN} = \pm 1V$	0.80	0.88	0.95	I	0.80	0.88	0.95	II	V/V
R_{IN}	Input Impedance	$T_{\rm J} = 25^{\circ}{\rm C}, V_{\rm IN} = \pm 1{\rm V}$	108	1011		I	10 ¹⁰	1011		I	Ω
R _{OUT}	Output Impedance	$V_{\mathrm{IN}} = \pm 1 V_{\mathrm{DC}},$ $\Delta R_{\mathrm{L}} = 50 \Omega \text{ to Infinity}$		4	8	I		4	10	II	Ω
v _o	Output Voltage Swing	$V_{\rm IN}=\pm 4V$	± 2.0	± 2.9		I	± 2.0	± 2.9		III	V
I_{IN}	Input Current	$T_{J} = 25^{\circ}C \text{ (Note 2)}$			250	I			500	I	pA
		T _A = 25°C (Note 3)			2.5	IV			5	IV	nA
		$T_{J} = T_{A} = T_{MAX}$			10	I			20	III	nA
PSRR	Power Supply Rejection Ratio	$V_S = \pm 5V \text{ to } \pm 15V$ $R_L = 1 \text{ k}\Omega$		60		v		60		v	dB
I _S	Supply Current	$R_{\rm L} = 1 \ { m k}\Omega$		17.5	20	I		17.5	20	II	mA

- Note 1: When operating at elevated temperatures the power dissipation of the EL2004 must be limited to the values shown in the typical performance curve "Maximum Power Dissipation vs Temperature". Junction to case thermal resistance is 31°C/W when dissipation is spread among the transistors in a normal AC steady-state condition. In special conditions where heat is concentrated in one output device, junction temperature should be calculated using a thermal resistance of 70°C/W.
- Note 2: Specification is at 25°C junction temperature due to requirements of high-speed automatic testing. Actual values at operating temperatures will exceed the value at $T_J=25$ °C. When supply voltages are ± 15 V, no-load operating junction temperatures may rise 40°C to 60°C above ambient and more under load conditions. Accordingly, V_{OS} may change one to several mV, and I_{IN} will change significantly during warm-up. Refer to I_{IN} vs Temperature graph for expected values.
- Note 3: Measured in still air seven minutes after application of power. See graph of Input Current During Warm-up for further information.
- Note 4: Bandwidth is calculated from the rise time. The EL2004 has a single pole gain and phase response up to the -3 dB frequency.
- Note 5: Slew rate is measured between $V_{\mbox{OUT}} = +2.5 \mbox{V}$ and $-2.5 \mbox{V}$ for this test.
- Note 6: Slew rate is measured between $V_{\mbox{OUT}}=+1V$ and -1V for this test. Pulse repetition rate is ≤ 50 MHz.

\pm 15V AC Electrical Characteristics

 $V_{S}=~\pm15V,\,R_{L}=1~k\Omega,\,R_{S}=50\Omega,\,T_{J}=~25^{\circ}C$ unless otherwise specified

				EI	2004						
Parameter	Description	Test Conditions	Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
BW	Bandwidth	(Note 4)	200	350		I	200	350		I	MHz
		$R_L = 50\Omega$	140	200		I	140	200		I	MHz
t _s	Settling Time to 1%	$\Delta V_{IN} = 1V, t_r = 3 \text{ ns}$		6		V		6		V	ns
C _{in}	Input Capacitance			3		v		3		v	pF

EL2004/EL2004C

350 MHz FET Buffer

\pm 15V AC Electrical Characteristics

 $\rm V_S=\,\pm\,15V, R_L=1\,k\Omega, R_S=50\Omega, T_J=25^{\circ}C$ unless otherwise specified — Contd.

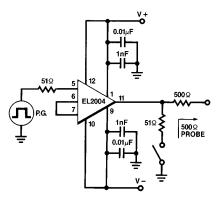
				EI	2004		EL2004C				
Parameter	Description	Test Conditions		Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
SR	Slew Rate	$V_{IN} = \pm 5V \text{ (Note 5)}$	2000	2500		I	2000	2500		I	V/μs
		$C_{L} = 100 \text{ pF}, V_{IN} = \pm 5V$ (Note 5)		1200		v		1200		v	V/μs
t _r	Rise Time	$\Delta V_{\mathrm{IN}} \sim 0.6 V$		1.0	1.7	I		1.0	1.7	I	ns
	Note: See Test Figure	$\Delta V_{\mathrm{IN}} \sim 0.6 \mathrm{V}, R_{\mathrm{L}} = 50 \Omega$		1.7	2.5	I		1.7	2.5	I	ns
t _p	Propagation Delay Note: See Test Figure	$\Delta V_{\rm IN} \sim 0.6 V$		1.0	2.0	I		1.0	2.0	I	ns
R _{OUT}	Output Impedance	$f = 1$ MHz, $V_{IN} = 1$ V_{RMS} $\Delta R_L = 100\Omega$ to Infinity		4		v		4		v	Ω
+PSRR	Power Supply Rejection Ratio	$\Delta V_S + = \pm 1.5 V_{peak}$ f = 1 kHz		40		v		40		v	dB
-PSRR	Power Supply Rejection Ratio	$\Delta V_S - = \pm 1.5 V_{peak}$ f = 1 kHz		40		v		40		v	dB

\pm 5V AC Electrical Characteristics

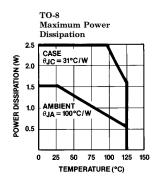
 $\rm V_S=\,\pm\,5V,\,R_L=\,50\Omega,\,R_S=\,50\Omega,\,T_J=\,25^{\circ}C$ unless otherwise specified

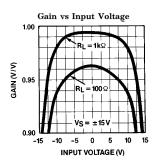
			EL2004				1				
Parameter	Description	Test Conditions	Min	Тур	Max	Test Level	Min	Тур	Max	Test Level	Units
BW	Bandwidth	$R_L = 1 k\Omega$	175	220		I	175	220		I	MHz
		(Note 4)	125	150		IV	125	150		IV	MHz
t _s	Settling Time to 1%	$\Delta V_{ m IN}=1V, t_{ m r}=3~{ m ns}$		8		V		8		v	ns
C _{in}	Input Capacitance			3		V		3		v	pF
SR	Slew Rate	$V_{IN} = \pm 2V \text{ (Note 6)}$	900	1200		I	900	1200		I	V/μs
		$C_{L} = 100 \text{ pF}, V_{IN} = \pm 2V$ $R_{L} = 1 \text{ k}\Omega \text{ (Note 6)}$		500		v		500		v	V/μs
t _r	Rise Time	$R_{L} = 1 k\Omega, \Delta V_{IN} \sim 0.6 V$		1.6	2.0	I		1.6	2.0	I	ns
	Note: See Test Figure	$R_{\rm L} = 50\Omega, \Delta V_{\rm IN} \sim 0.6V$		2.3	2.8	IV		2.3	2.8	IV	ns
t _p	Propagation Delay Note: See Test Figure	$R_{L}=1~k\Omega, \Delta V_{IN}\sim 0.6V$		1.2	2.4	I		1.2	2.4	I	ns
R _{OUT}	Output Impedance	$\label{eq:force_force} \begin{cases} f = 1 \text{ MHz}, V_{IN} = 1 V_{RMS} \\ \Delta R_L = 100\Omega \text{ to Infinity} \end{cases}$		4		v		4		v	Ω
+PSRR	Power Supply Rejection Ratio	$\Delta V_{S}-=\pm 0.5 V_{peak}$ f = 1 kHz		30		v		30		v	dB
-PSRR	Power Supply Rejection Ratio	$\Delta V_S + = \pm 0.5 V_{peak}$ f = 1 kHz		30		v		30		v	dB

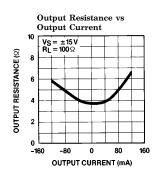
AC Test Circuit



Typical Performance Curves

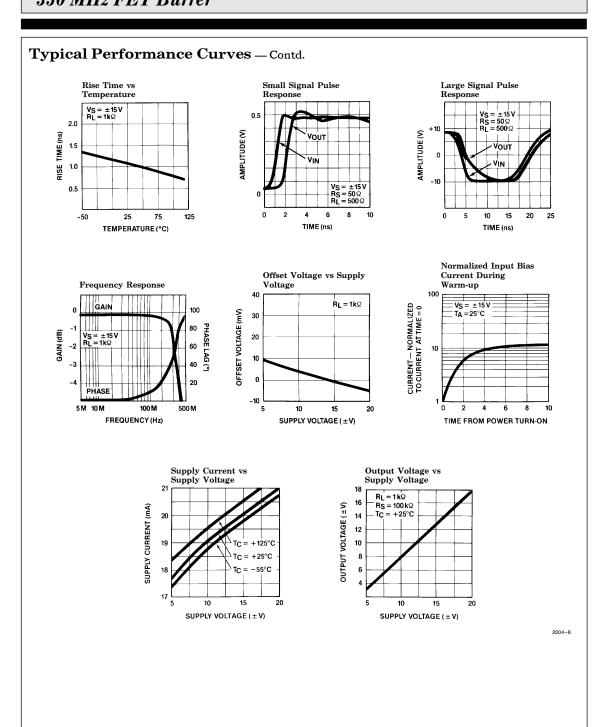






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2004-



Applications Information

The EL2004 is one member of a family of high performance buffers manufactured by Elantec. The 2004 is optimized for speed while others offer choices of input DC parameters or output drive or cost. The following table illustrates those members available at the time of this printing. Consult the factory for the latest capabilities in this developing line.

Elantec's Buffer Family

Part #	Slew Rate V/μs	Bandwidth MHz	Input Current (Warm)	Peak I _{OUT} mA	Rise Time ns
ELH0002	200	50	6 μΑ	400	7
ELH0033	1500	100	2.5 nA	250	2.9
EL2004	2500	350	2.5 nA	250	1.0
EL2005	1500	140	0.1 nA	250	2.5

Recommended Layout Precautions

The very high-speed performance of the EL2004 can only be realized by taking certain precautions in circuit layout and power supply decoupling. Low inductance ceramic chip or disc power supply decoupling capacitors of 0.1 μF or more should be connected with the shortest practical lead lengths between the device supply leads and a ground plane. In addition, it can be helpful to parallel these with 4.7 μF electrolytics (Tantalum preferred). Failure to follow these precautions can result in oscillation.

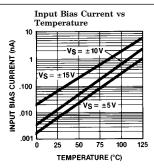
Circuit Operation

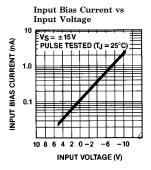
The EL2004 is effectively an ideal unity gain amplifier with almost infinite input impedance and about 6Ω output impedance.

Input Characteristics

The input impedance of a junction FET is a strong function of temperature and input voltage. Nominal input resistance of EL2004 is 10^{12} at 25°C junction, but as I_B doubles every 11°C in the JFET, the input resistance falls. During warm-up, self-heating raises the junction temperature up to 60°C or more (without heatsink) so operating I_B will be much higher than the data sheet 25°C specification.

Another factor which can increase bias current is input voltage. If the input voltage is more than 20V below the positive supply, the input current rises exponentially. (See Curve.)





2004-

In applications such as sample and hold circuits where it is important to maintain low input bias current over input voltage range, the EL2005 High Accuracy Fast Buffer is recommended.

The input capacitance of EL2004 comprises the FET device gate-to-source capacitance (which is a function of input voltage) and stray capacitance to the case. Effective input capacitance can be minimized by connecting the case to the output since it is electrically isolated. Or, for reduced radiation, the case may be grounded. The AC characteristics specified in this data sheet were obtained with the case floating.

Offset Voltage Adjustment

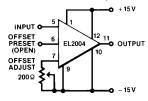
The EL2004's offset voltages have been actively laser trimmed at $\pm 15 V$ supplies to meet specified limits when the offset adjust pin is shorted to the offset preset pin. If external offset null is required, the offset adjust pin should be connected to a 200Ω trim pot connected to the negative supply.

EL2004/EL2004C

350 MHz FET Buffer

Circuit Operation — Contd.

Offset Zero Adjust



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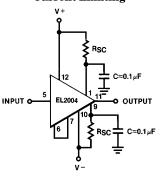
Capacitive Loading

The EL2004 is designed to drive capacitive loads up to several thousand picofarads without oscillation. However, peak current resulting from charging currents on fast edges should be limited below the absolute maximum peak current rating of 250 mA. In some cases it may be necessary to employ one of the current limit schemes shown below.

Short Circuit Protection

Dynamic response of the EL2004 was preserved by excluding current limit circuits which are not needed in most applications. However, in situations where operating conditions are not controlled, short circuit protection can be added by inserting resistors between the output device collectors and supplies as illustrated.

Using Resistor Current Limiting

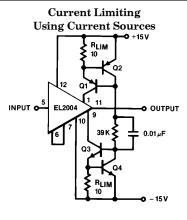


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Suitable resistor values can be calculated as follows:

$$R_{SC} = \frac{V+}{I_{SC}} = \frac{V-}{I_{SC}}$$

where $I_{SC} \leq 100$ mA for EL2004.



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The inclusion of limiting resistors in the collectors of the output devices will reduce the output voltage swing and speed. Decoupling V_C+ and V_C- pins with capacitors to ground will retain full output swing for transient pulses.

An alternate active current limit technique that retains full DC output swing is shown above. Here the current sources are saturated during normal operation thus applying full supply voltage to the $V_{\rm C}$ pins. Under fault conditions, the voltage decreases as the current source reaches its limit.

$$R_{LIM} = \frac{V_{BE}}{I_{SC}} = \frac{0.6V}{100 \; mA} = 6\Omega \label{eq:RLIM}$$

Power Supplies

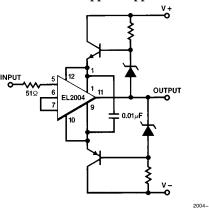
The EL2004 has been characterized for both ± 15 and ± 5 V dual supply operation, but other combinations can also be useful. For example, in many video applications it is only necessary for the output to swing ± 2 V or less, but speed and distortion are important. In this situation, the input stage can be operated at the full ± 15 V supply while the output collectors are returned to ± 5 V. The speed and distortion will be almost as good as if the whole circuit was operating at ± 15 V, but the dissipation is substantially reduced and higher load currents can be safely accommodated

Circuit Operation — Contd.

Increasing Operating Voltage and Reducing Thermal Tail

When driving heavy loads, the changing dissipation in the output transistors can sometimes cause temperature gradients in the circuit which cause a shift in offset voltage and the phenomenon known as "thermal tail". Bootstrapping the output as illustrated substantially reduces the power in the output transistors and mitigates the effect.

High Voltage Inputs can be Accommodated with Bootstrapped Supplies



Hardware

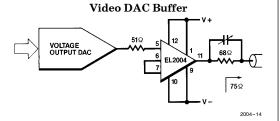
In order to utilize the full drive capabilities of the EL2004, it should be mounted with a heatsink, particularly for extended temperature operation. Suitable heatsinks include Thermalloy 2240A (33°C/W), Wakefield 215CB (30°C/W) and IERC-UP-TO-848CB (15°C/W).

The case is isolated from the circuit and may be connected to system chassis. Sockets are not recommended as they add substantial inductance and capacitance which impair the performance of the device. However, for test purposes they are unavoidable and precautions such as shielding input from output are suggested.

General Application Suggestions

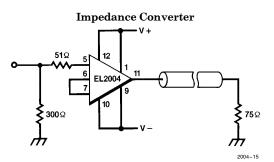
Video DAC Buffer

Many of the available video D to A converters are unable to directly drive 50Ω or 75Ω cables. The EL2004's excellent phase linearity at video frequencies make it an ideal solution. In critical applications or where line termination is not controlled, a matching pad should be used as shown. The capacitor should be adjusted for optimum pulse response. If properly layed out this circuit will not overshoot.



Impedance Matching

The EL2004 provides power gain and isolation between source and load when used as an active tap or impedance matching device as illustrated here. In this example, there is no output matching pad between the 2004 and the 75Ω line. Such matching is not needed when the distant end of the cable is properly terminated as there is no reflected signal to worry about and the 2004 isolates the source. This technique allows the full output voltage of the EL2004 to be applied to the load.

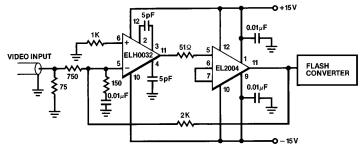


EL2004/EL2004C

350 MHz FET Buffer

${\bf General\ Application\ Suggestions-Contd.}$

Inverting Amplifier for 20 MHz Flash Converter



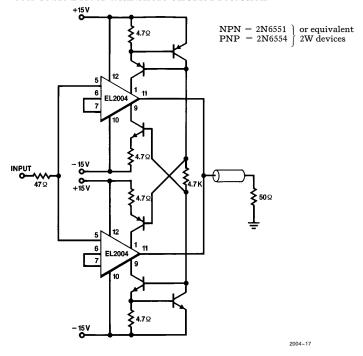
Boosting the Output

Unlike most integrated cicuits, two or more EL2004's can be paralleled for increased output drive. This capability results from the finite output resistance and low output mismatch of the

EL2004. For example, a 50Ω cable driver with $\pm 10V$ capability can be made by using two EL2004's. A short-circuit protected version is shown below.

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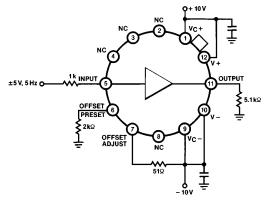
50Ω Cable Driver with Short Circuit Protection



10

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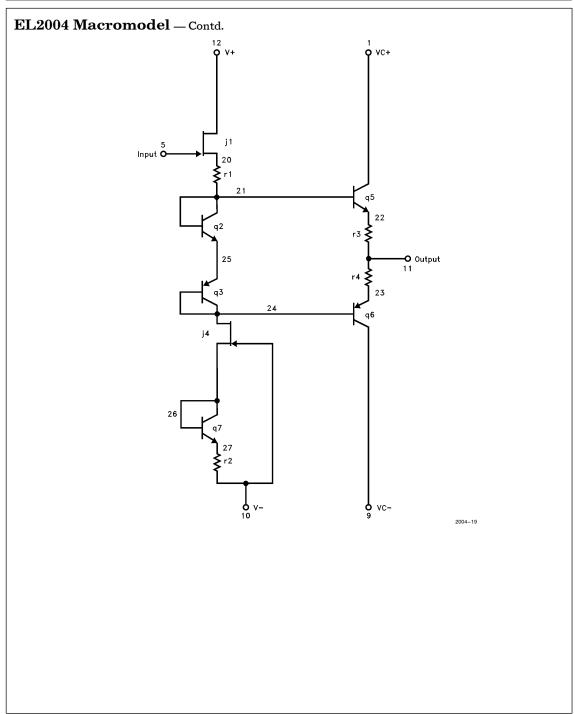
Burn-In Circuit



Pin numbers are for TO-8 package. LCC uses the same schematic.

EL2004 Macromodel

```
* Connections: input
                          v +
                                 v_c +
                                               Vc-
                                                      output
.subckt M2004 5
.model qn npn (is = 5e – 14 bf = 150 vaf = 100 rc = 1 rb = 5 re = 1 ikf = 200mA
+ \text{cje} = 5\text{pF cjc} = 5\text{pF mje} = .42 \text{ mjc} = .23 \text{ tf} = .3\text{nS tr} = 200\text{nS br} = 5 \text{ vtf} = 0
.model qp pnp (is = 5e - 14 bf = 150 vaf = 100 rc = 2 rb = 3 re = 1 ikf = 100mA
+\,cje=5.7pF\,\,cjc=4pF\,\,tf=.3nS\,\,mje=.32\,\,mjc=.43\,\,tr=170nS\,\,br=5\,\,vtf=0)
.model qf njf (vto = -3V beta = 4.0e-3 cgd = 4pF cgs = 10pF lambda = 671.0e-6)
* Resistors
r1 20 21 58.33
r2 27 10 58.33
r3 22 11 2
r4 11 23 2
* Transistors
j1 12 5 20 qf
j4 24 10 26 qf
q2 21 21 25 qn
q3 24 24 25 qp
q5 1 21 22 qn
q6 9 24 23 qp
q7\ 26\ 26\ 27\ qn
.ends
```



General Disclaimer

Specifications contained in this data sheet are in effect as of the publication date shown. Elantec, Inc. reserves the right to make changes in the circuitry or specifications contained herein at any time without notice. Elantec, Inc. assumes no responsibility for the use of any circuits described herein and makes no representations that they are free from patent infringement.



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WARNING — Life Support Policy

Elantec, Inc. products are not authorized for and should not be used within Life Support Systems without the specific written consent of Elantec, Inc. Life Support systems are equipment intended to support or sustain life and whose failure to perform when properly used in accordance with instructions provided can be reasonably expected to result in significant personal injury or death. Users contemplating application of Elantec, Inc. products in Life Support Systems are requested to contact Elantec, Inc. factory headquarters to establish suitable terms & conditions for these applications. Elantec, Inc.'s warranty is limited to replacement of defective components and does not cover injury to persons or property or other consequential damages.

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